

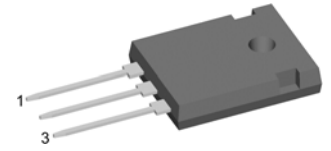
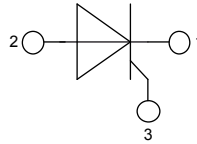
High Efficiency Thyristor

Single Thyristor

$V_{RRM} = 1200 \text{ V}$
 $I_{T(AV)M} = 30 \text{ A}$
 $I_{T(RMS)} = 47 \text{ A}$

Part number

CLA 30 E 1200 HB



Backside: anode

Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

Applications:

- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package:

- Housing: TO-247
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Ratings

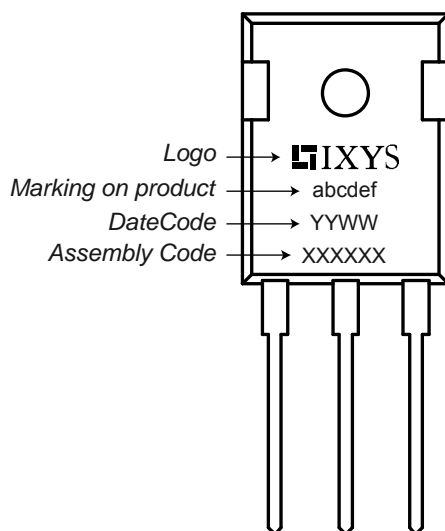
Symbol	Definition	Conditions	Ratings			Unit	
			min.	typ.	max.		
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^{\circ}\text{C}$			1300	V	
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^{\circ}\text{C}$			1200	V	
I_{RD}	reverse current, drain current	$V_{RD} = 1200 \text{ V}$			10	μA	
		$V_{RD} = 1200 \text{ V}$			2	mA	
V_T	forward voltage drop	$I_T = 30 \text{ A}$			1.28	V	
		$I_T = 60 \text{ A}$			1.56	V	
		$I_T = 30 \text{ A}$	$T_{VJ} = 125^{\circ}\text{C}$			1.25	V
		$I_T = 60 \text{ A}$	$T_{VJ} = 125^{\circ}\text{C}$			1.61	V
$I_{T(AV)M}$	average forward current	$T_C = 120^{\circ}\text{C}$			30	A	
$I_{T(RMS)}$	RMS forward current	180° sine			47	A	
V_{T0}	threshold voltage	} for power loss calculation only	$T_{VJ} = 150^{\circ}\text{C}$		0.86	V	
r_T	slope resistance				12.5	m Ω	
R_{thJC}	thermal resistance junction to case				0.55	K/W	
T_{VJ}	virtual junction temperature		-40		150	$^{\circ}\text{C}$	
P_{tot}	total power dissipation	$T_C = 25^{\circ}\text{C}$			190	W	
P_{GM}	max. gate power dissipation	$t_p = 30 \mu\text{s}$	$T_C = 150^{\circ}\text{C}$		10	W	
		$t_p = 300 \mu\text{s}$			5	W	
P_{GAV}	average gate power dissipation				0.5	W	
I_{TSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$	$T_{VJ} = 45^{\circ}\text{C}$		300	A	
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$	$V_R = 0 \text{ V}$		325	A	
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$	$T_{VJ} = 150^{\circ}\text{C}$		255	A	
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$	$V_R = 0 \text{ V}$		275	A	
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$	$T_{VJ} = 45^{\circ}\text{C}$		450	A ² s	
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$	$V_R = 0 \text{ V}$		440	A ² s	
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$	$T_{VJ} = 150^{\circ}\text{C}$		325	A ² s	
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$	$V_R = 0 \text{ V}$		315	A ² s	
C_J	junction capacitance	$V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}\text{C}$		13	pF	

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
$(di/dt)_{cr}$	<i>critical rate of rise of current</i>	$T_{VJ} = 150\text{ }^{\circ}\text{C}$ repetitive, $I_T = 40\text{ A}$ $f = 50\text{ Hz}$; $t_p = 200\text{ }\mu\text{s}$ $I = 0.3\text{ A}$; $di/dt = 0.3\text{ A}/\mu\text{s}$			150	$\text{A}/\mu\text{s}$
		$V_D = \frac{2}{3} V_{DRM}$ non-repetitive, $I_T = 30\text{ A}$			500	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	<i>critical rate of rise of voltage</i>	$V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = 150\text{ }^{\circ}\text{C}$ $R_{GK} = \infty$; method 1 (linear voltage rise)			500	$\text{V}/\mu\text{s}$
V_{GT}	<i>gate trigger voltage</i>	$V_D = 6\text{ V}$ $T_{VJ} = 25\text{ }^{\circ}\text{C}$ $T_{VJ} = -40\text{ }^{\circ}\text{C}$			1.3	V
I_{GT}	<i>gate trigger current</i>	$V_D = 6\text{ V}$ $T_{VJ} = 25\text{ }^{\circ}\text{C}$ $T_{VJ} = -40\text{ }^{\circ}\text{C}$			1.6	V
					28	mA
V_{GD}	<i>gate non-trigger voltage</i>	$V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = 150\text{ }^{\circ}\text{C}$			0.2	V
I_{GD}	<i>gate non-trigger current</i>				1	mA
I_L	<i>latching current</i>	$t_p = 10\text{ }\mu\text{s}$ $T_{VJ} = 25\text{ }^{\circ}\text{C}$ $I = 0.3\text{ A}$; $di/dt = 0.3\text{ A}/\mu\text{s}$			90	mA
I_H	<i>holding current</i>	$V_D = 6\text{ V}$ $R_{GK} = \infty$ $T_{VJ} = 25\text{ }^{\circ}\text{C}$			60	mA
t_{gd}	<i>gate controlled delay time</i>	$V_D = \frac{1}{2} V_{DRM}$ $T_{VJ} = 25\text{ }^{\circ}\text{C}$ $I = 0.3\text{ A}$; $di/dt = 0.3\text{ A}/\mu\text{s}$			2	μs
t_q	<i>turn-off time</i>	$V_R = 100\text{ V}$; $I_T = 30\text{ A}$ $T_{VJ} = 150\text{ }^{\circ}\text{C}$ $V_D = \frac{2}{3} V_{DRM}$; $t_p = 200\text{ }\mu\text{s}$ $di/dt = 10\text{ A}/\mu\text{s}$; $dv/dt = 20\text{ V}/\mu\text{s}$		150		μs

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
I_{RMS}	RMS current	per terminal			50	A
R_{thCH}	thermal resistance case to heatsink			0.25		K/W
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N

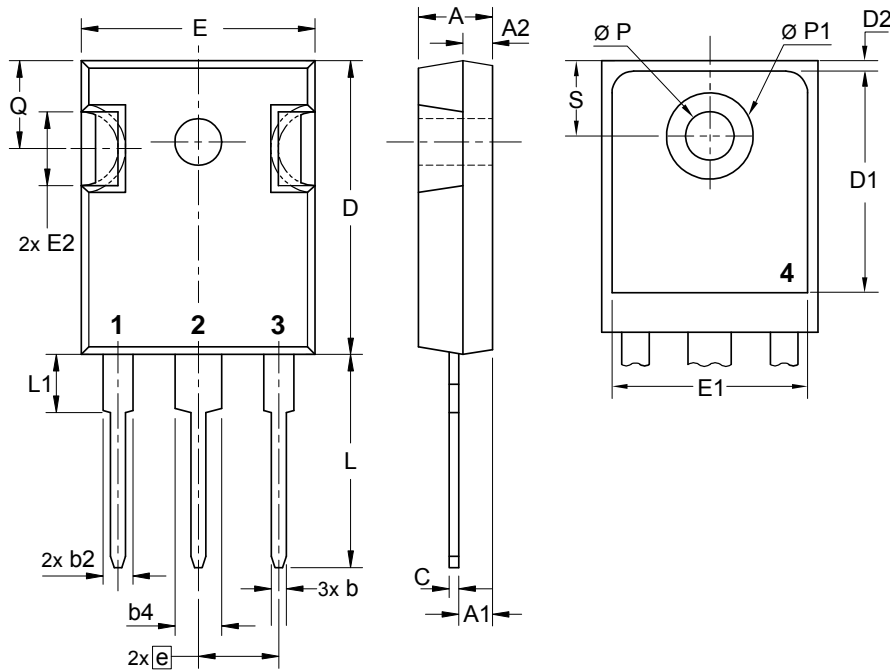
Part number

- C = Thyristor (SCR)
- L = High Efficiency Thyristor
- A = (up to 1200 V)
- 30 = Current Rating [A]
- E = Single Part
- 1200 = Reverse Voltage [V]
- HB = TO-247AD (3)

Product Marking


Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	CLA 30 E 1200 HB	CLA30E1200HB	Tube	30	508221

Similar Part	Package	Voltage class
CLA30E1200PB	TO-220AB (3)	1200
CLA30E1200PC	TO-263AB (D2Pak)	1200
CS22-12io1M	TO-220ABFP (3)	1200
CS22-08io1M	TO-220ABFP (3)	800
CMA30E1600PN	TO-220ABFP (3)	1600
CMA30E1600PB	TO-220AB (3)	1600

Outlines TO-247


Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215 BSC		5.46 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39

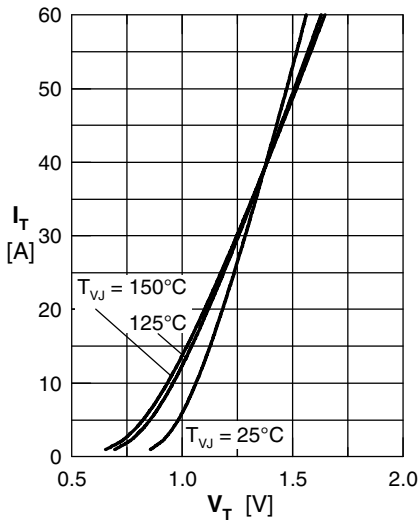


Fig. 1 Forward characteristics

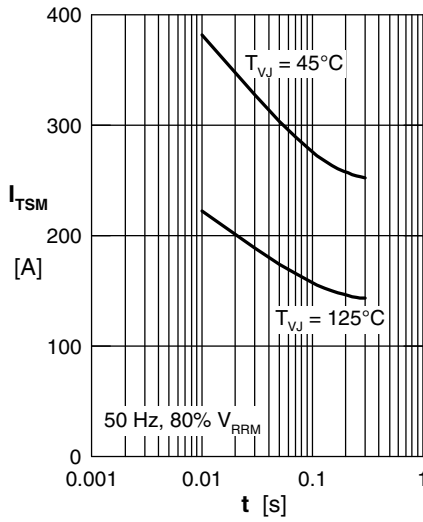


Fig. 2 Surge overload current I_{TSM} : crest value, t: duration

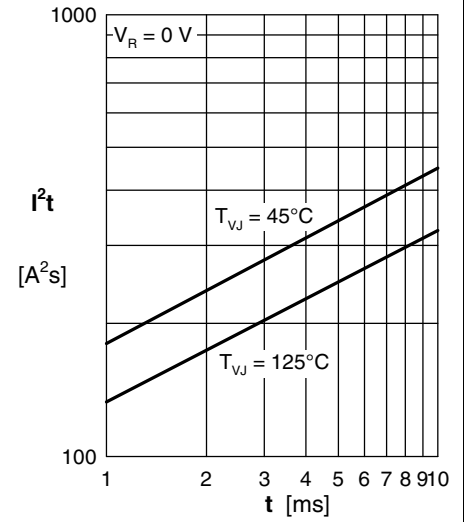


Fig. 3 I^2t versus time (1-10 s)

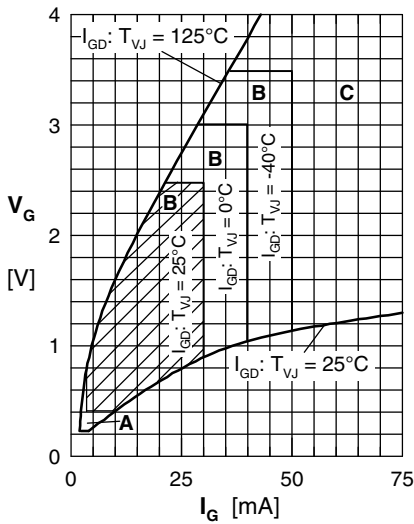


Fig. 4 Gate voltage & gate current
Triggering: A = no; B = possible; C = safe

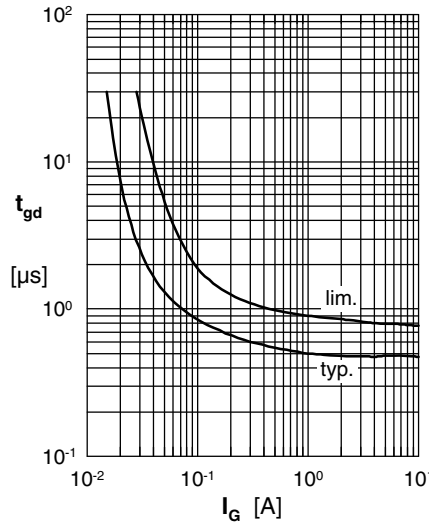


Fig. 5 Gate controlled delay time t_{gd}

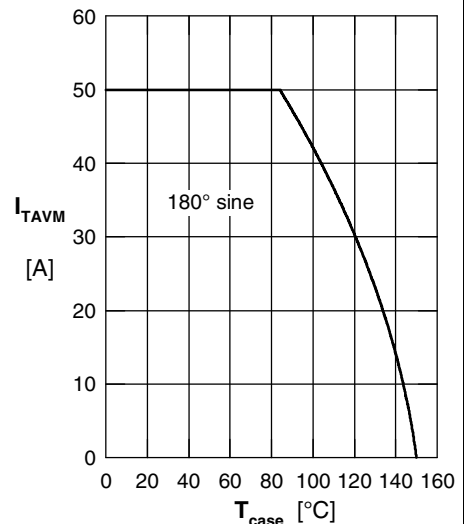


Fig. 6 Max. forward current at case temperature

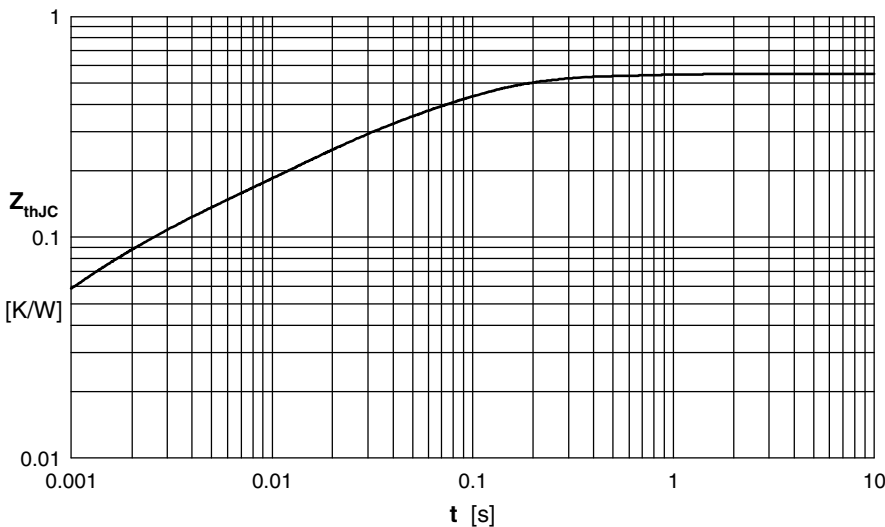


Fig. 7 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.024	0.0005
2	0.059	0.0018
3	0.128	0.014
4	0.306	0.08
5	0.033	0.56